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Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.0027			
I _D (A)	100			
Configuration	Single			
Package	TO-263			



FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified d
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



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N-Channel MOSFET	S

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	40	V
Gate-Source Voltage		V_{GS}	± 20	V
Continuous Drain Current	T _C = 25 °C ^a	I _D	100	
Continuous Drain Current	T _C = 125 °C		98	
Continuous Source Current (Diode Condu	ction) ^a	I _S	100	Α
Pulsed Drain Current ^b		I _{DM}	400	
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	70	
Single Pulse Avalanche Energy	L = U. I MIH	E _{AS}	245	mJ
Maximum Power Dissipation ^b	T _C = 25 °C	В	157	W
	T _C = 125 °C	P_{D}	52	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount c	R_{thJA}	40	°C/W	
Junction-to-Case (Drain)		R_{thJC}	0.95	C/VV	

Notes

- a. Package limited.
- b. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- c. When mounted on 1" square PCB (FR4 material).
- d. Parametric verification ongoing.



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SPECIFICATIONS (T _C = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-Source Breakdown Voltage	V_{DS}	V _{GS}	= 0, I _D = 250 μA	40	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μA	2.5	3.0	3.5	V
Gate-Source Leakage	I_{GSS}	V _{DS} =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1	
Zero Gate Voltage Drain Current	I_{DSS}	V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μΑ
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	250	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	V _{DS} ≥ 5 V	120	-	-	Α
		V _{GS} = 10 V	I _D = 30 A	-	0.00225	0.00270	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A, T _J = 125 °C	-	-	0.00440	Ω
		V _{GS} = 10 V	I _D = 30 A, T _J = 175 °C	-	-	0.00540	
Forward Transconductance b	9 _{fs}	V_{DS}	V _{DS} = 15 V, I _D = 30 A		201	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			-	6325	7910	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	744	930	pF
Reverse Transfer Capacitance	C _{rss}				314	395	
Total Gate Charge ^c	Qg			-	95.5	145	
Gate-Source Charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 100 \text{ A}$	-	25.5	-	nC
Gate-Drain Charge ^c	Q_{gd}			-	14.7	-	
Gate Resistance	R_g		f = 1 MHz	0.7	1.48	3.8	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	14	21	
Rise Time ^c	t _r	V_{DD} = 20 V, R_L = 0.2 Ω I_D \cong 100 A, V_{GEN} = 10 V, R_g = 1 Ω		-	11	17	ns
Turn-Off Delay Time ^c	t _{d(off)}			-	48	72	
Fall Time ^c	t _f			-	9	14	
Source-Drain Diode Ratings and Characteristics b							
Pulsed Current ^a	I _{SM}			-	-	400	Α
Forward Voltage	V _{SD}	I _F = 30 A, V _{GS} = 0		-	0.8	1.5	V

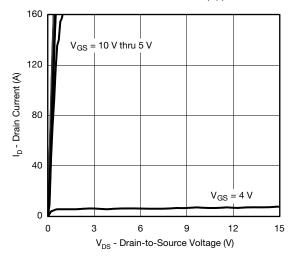
Notes

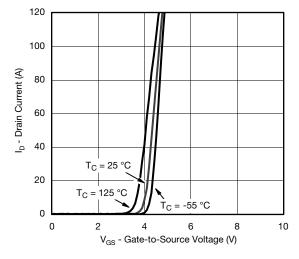
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



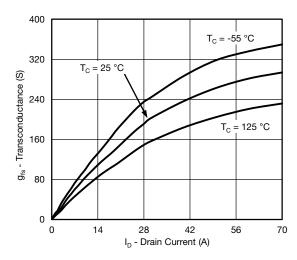
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

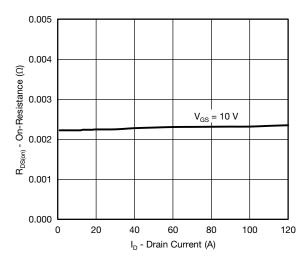




Output Characteristics

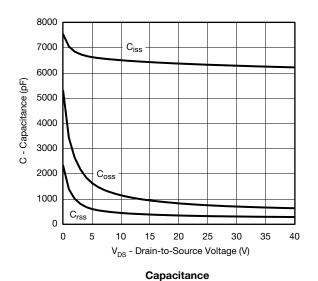


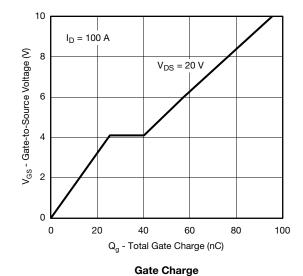




Transconductance

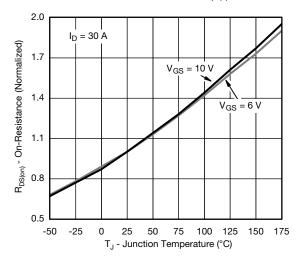
On-Resistance vs. Drain Current



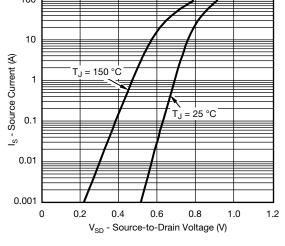




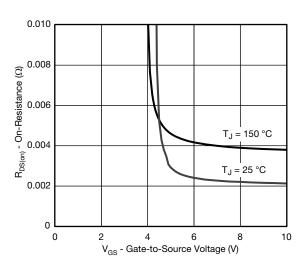
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



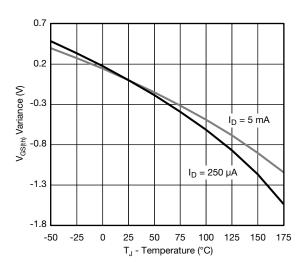
On-Resistance vs. Junction Temperature



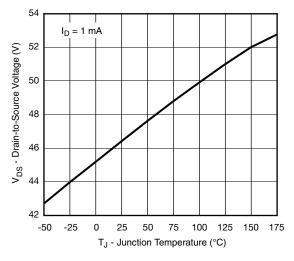
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

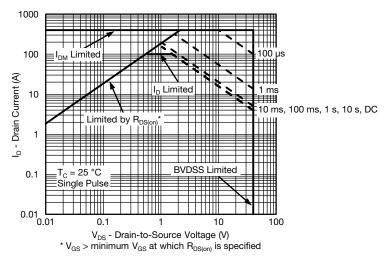


Drain Source Breakdown vs. Junction Temperature

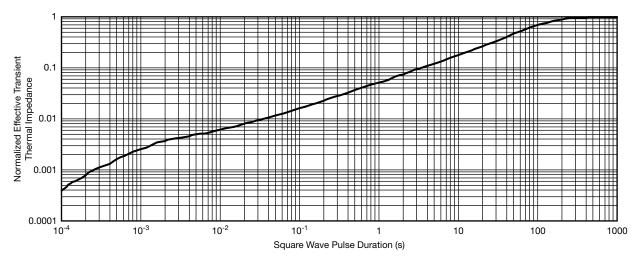
For technical questions, contact: automostech



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



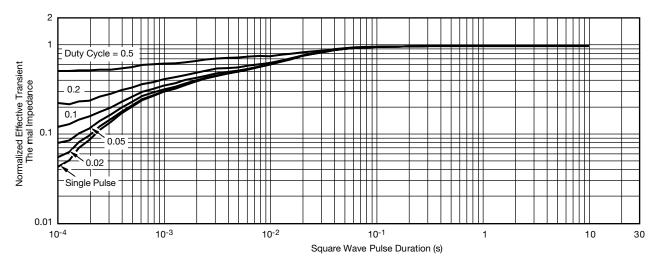
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg262769.



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REVISION	REVISION HISTORY ^a				
REVISION	DATE	DESCRIPTION OF CHANGE			
В	04-Aug-15	Revised R _g minimum limit			

Note

a. As of April 2014

Vishay Siliconix

D²PAK / TO-263 and TO-262

Ordering codes for the SQ rugged series power MOSFETs in the D²PAK / TO-263 and TO-262 packages:

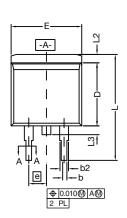
DATASHEET PART NUMBER	OLD ORDERING CODE ^a	NEW ORDERING CODE		
SQM100N04-2m7	SQM100N04-2M7-GE3	SQM100N04-2M7_GE3		
SQM100N10-10	SQM100N10-10-GE3	SQM100N10-10_GE3		
SQM110N05-06L	SQM110N05-06L-GE3	SQM110N05-06L_GE3		
SQM110P06-8m9L	SQM110P06-8M9L-GE3	SQM110P06-8M9L_GE3		
SQM120N02-1m3L	SQM120N02-1M3L-GE3	SQM120N02-1M3L_GE3		
SQM120N03-1m5L	SQM120N03-1M5L-GE3	SQM120N03-1M5L_GE3		
SQM120N04-1m7	SQM120N04-1M7-GE3	SQM120N04-1M7_GE3		
SQM120N04-1m7L	SQM120N04-1M7L-GE3	SQM120N04-1M7L_GE3		
SQM120N04-1m9	SQM120N04-1M9-GE3	SQM120N04-1M9_GE3		
SQM120N06-06	SQM120N06-06-GE3	SQM120N06-06_GE3		
SQM120N06-3m5L	SQM120N06-3M5L-GE3	SQM120N06-3M5L_GE3		
SQM120N10-09	SQM120N10-09-GE3	SQM120N10-09_GE3		
SQM120N10-3m8	SQM120N10-3M8-GE3	SQM120N10-3M8_GE3		
SQM120P04-04L	SQM120P04-04L-GE3	SQM120P04-04L_GE3		
SQM120P06-07L	SQM120P06-07L-GE3	SQM120P06-07L_GE3		
SQM120P10-10m1L	-	SQM120P10_10m1LGE3		
SQM200N04-1m1L	SQM200N04-1M1L-GE3	SQM200N04-1M1L_GE3		
SQM200N04-1m7L	SQM200N04-1M7L-GE3	SQM200N04-1M7L_GE3		
SQM200N04-1m8	SQM200N04-1M8-GE3	SQM200N04-1M8_GE3		
SQM25N15-52	SQM25N15-52-GE3	SQM25N15-52_GE3		
SQM35N30-97	SQM35N30-97-GE3	SQM35N30-97_GE3		
SQM40010EL	-	SQM40010EL_GE3		
SQM40N10-30	SQM40N10-30-GE3	SQM40N10-30_GE3		
SQM40N15-38	SQM40N15-38-GE3	SQM40N15-38_GE3		
SQM40P10-40L	SQM40P10-40L-GE3	SQM40P10-40L_GE3		
SQM47N10-24L	SQM47N10-24L-GE3	SQM47N10-24L_GE3		
SQM50020EL	-	SQM50020EL_GE3		
SQM50N04-4m0L	SQM50N04-4M0L-GE3	SQM50N04-4M0L_GE3		
SQM50N04-4m1	SQM50N04-4M1-GE3	SQM50N04-4M1_GE3		
SQM50P03-07	SQM50P03-07-GE3	SQM50P03-07_GE3		
SQM50P04-09L	SQM50P04-09L-GE3	SQM50P04-09L_GE3		
SQM50P06-15L	SQM50P06-15L-GE3	SQM50P06-15L_GE3		
SQM50P08-25L	SQM50P08-25L-GE3	SQM50P08-25L_GE3		
SQM60030E	-	SQM60030E_GE3		
SQM60N06-15	SQM60N06-15-GE3	SQM60N06-15_GE3		
SQM60N20-35	SQM60N20-35-GE3	SQM60N20-35_GE3		
SQM70060EL	-	SQM70060EL_GE3		
SQM85N15-19	SQM85N15-19-GE3	SQM85N15-19_GE3		
SQV120N10-3m8	SQV120N10-3m8-GE3	SQV120N10-3m8_GE3		
SQV120N06-4m7L	-	SQV120N06-4m7L_GE3		

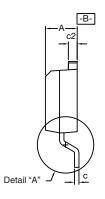
Note

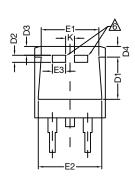
a. Old ordering code is obsolete and no longer valid for new orders



TO-263 (D²PAK): 3-LEAD

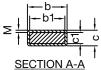








DETAIL A (ROTATED 90°)



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	SECTION A.	Ţ

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

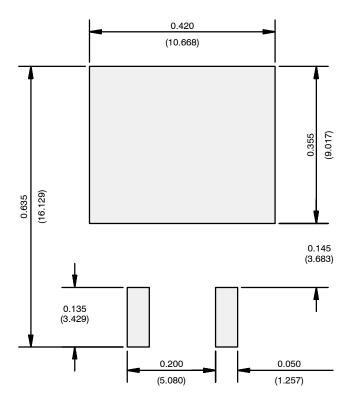
		INCHES		MILLIN	METERS
DIM.		MIN.	MAX.	MIN.	MAX.
	Α	0.160	0.190	4.064	4.826
	b	0.020	0.039	0.508	0.990
	b1	0.020	0.035	0.508	0.889
	b2	0.045	0.055	1.143	1.397
c*	Thin lead	0.013	0.018	0.330	0.457
C	Thick lead	0.023	0.028	0.584	0.711
c1	Thin lead	0.013	0.017	0.330	0.431
CI	Thick lead	0.023	0.027	0.584	0.685
	c2	0.045	0.055	1.143	1.397
	D	0.340	0.380	8.636	9.652
	D1	0.220	0.240	5.588	6.096
	D2	0.038	0.042	0.965	1.067
	D3	0.045	0.055	1.143	1.397
	D4	0.044	0.052	1.118	1.321
	Е	0.380	0.410	9.652	10.414
	E1	0.245	-	6.223	=
	E2	0.355	0.375	9.017	9.525
	E3	0.072	0.078	1.829	1.981
	е	0.100 BSC		2.54 BSC	
	K	0.045	0.055	1.143	1.397
	L	0.575	0.625	14.605	15.875
	L1	0.090	0.110	2.286	2.794
	L2	0.040	0.055	1.016	1.397
L3		0.050	0.070	1.270	1.778
	L4	0.010 BSC		0.254 BSC	
	М	-	0.002	-	0.050
ECN: T13-0707-Rev. K, 30-Sep-13					

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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